P54/74FCT373/A/C (P54/74PCT373/A/C)
P54/74FCT573/A/C (P54/74PCT573/A/C)
OCTAL TRANSPARENT LATCHES WITH 3-STATE OUTPUTS

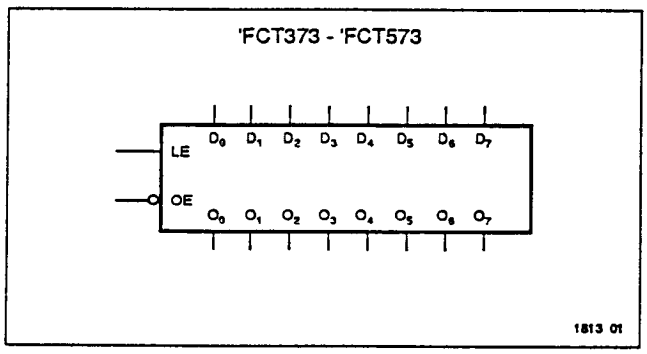
FEATURES

- Function, Pinout, and Drive Compatible with the FCT and F Logic
- FCT-C speed at 4.2ns max. (Com'l)
  FCT-A speed at 5.2ns max. (Com'l)
- CMOS V_{OH} Levels for Low Power Consumption — Typically 1/3 of FAST Bipolar Logic
- Edge-rate Control Circuitry for Significantly Improved Noise Characteristics
- ESD protection exceeds 2000V
- Inputs and Outputs Interface Directly with TTL, NMOS, and CMOS Devices
- Outputs Meet Levels Required for CMOS Static RAM Low Power Standby Mode
- 64 mA Sink Current (Com'l), 48 mA (Mil)
  15 mA Source Current (Com'l), 12 mA (Mil)
- Manufactured in 0.8 micron PACE Technology™

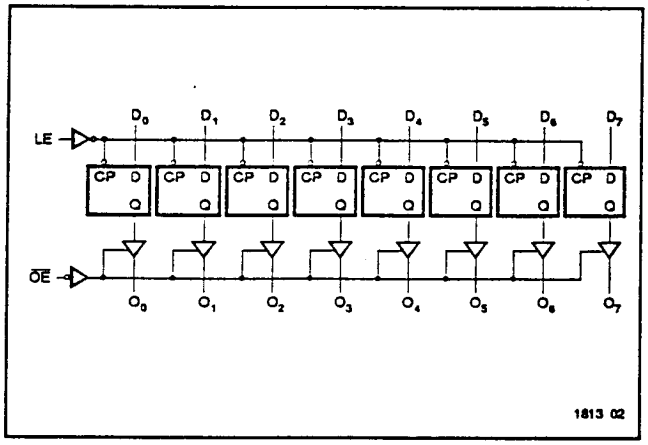
DESCRIPTION

The 'FCT373 and 'FCT573 consists of eight latches with 3-state outputs for bus organized system applications. When latch enable (LE) is HIGH, the flip flops appear transparent to the data. Data that meets the required set-up times are latched when LE transitions from HIGH to LOW. Data appears on the bus when the output enable ($\overline{OE}$) is LOW. When output enable is HIGH, the bus output is in the high impedance state. In this mode, data may be entered into the latches. The 'FCT573 is the same as the 'FCT373, except that the outputs are inverted. The 'FCT573 is identical to 'FCT373 except that all the inputs are on one side of the package and the outputs on the other side.

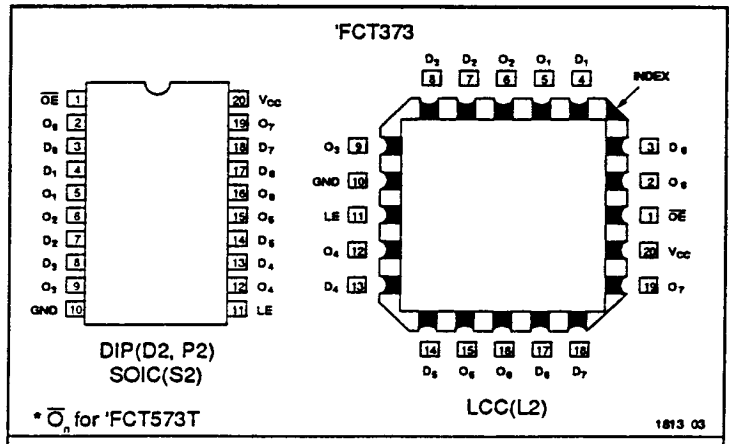
LOGIC SYMBOL

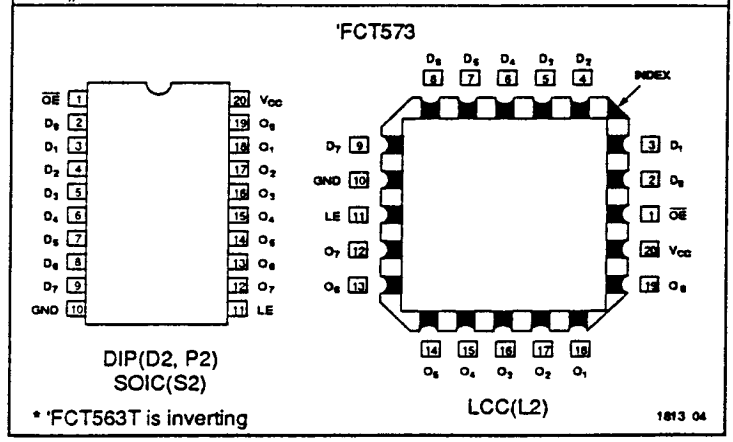


LOGIC DIAGRAM ('FCT373 – 'FCT573)



PIN CONFIGURATIONS





PERFORMANCE SEMICONDUCTOR CORPORATION

Means Quality, Service and Speed

ABSOLUTE MAXIMUM RATINGS[1,2]

Symbol	Parameter	Value	Unit
T_{STG}	Storage Temperature	–65 to +150	°C
T_A	Ambient Temperature Under Bias	–65 to +135	°C
V_{CC}	V_{CC} Potential to Ground	–0.5 to +7.0	V
I_{IN}	Input Current	–30 to +5.0	mA

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Symbol	Parameter	Value	Unit
I_{OUTPUT}	Current Applied to Output	120	mA
V_{IN}	Input Voltage	–0.5 to V_{CC} + 0.5	V
V_{OUT}	Voltage Applied to Output	–0.5 to V_{CC} + 0.5	V

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Notes:

1. Operation beyond the limits set forth in the above table may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature range.
2. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V_{CC} or ground.

RECOMMENDED OPERATING CONDITIONS

Free Air Ambient Temperature	Min	Max
Military	–55°C	+125°C
Commercial	0°C	+70°C

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Supply Voltage (V_{CC})	Min	Max
Military	+4.5V	+5.5V
Commercial	+4.75V	+5.25V

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DC ELECTRICAL CHARACTERISTICS (Over recommended operating conditions)

Symbol	Parameter		Min	Typ[1]	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		
V_{IL}	Input LOW Voltage				0.8	V		
V_H	Hysteresis			0.35		V		All inputs
V_{CD}	Input Clamp Diode Voltage			–0.7	–1.2	V	MIN	I_{IN} = –18mA
V_{OH}	Output HIGH Voltage	V_{CC} = 3V, V_{IN} = 0.2V, or V_{CC} – 0.2V	V_{CC} – 0.2	V_{CC}		V		I_{OH} = –32µA
		Military/Commercial (CMOS)	V_{CC} – 0.2	V_{CC}		V	MIN	I_{OH} = –300µA
		Military (TTL)	2.4	4.3		V	MIN	I_{OH} = –12mA
		Commercial (TTL)	2.4	4.3		V	MIN	I_{OH} = –15mA
V_{OL}	Output LOW Voltage	V_{CC} = 3V, V_{IN} = 0.2V, or V_{CC} – 0.2V		GND	0.2	V		I_{OL} = 300µA
		Military/Commercial (CMOS)		GND	0.2	V	MIN	I_{OL} = 300µA
		Military (TTL)		0.3	0.5	V	MIN	I_{OL} = 32mA
		Commercial (TTL)		0.3	0.5	V	MIN	I_{OL} = 48mA
		Commercial (TTL)		0.3	0.5	V	MIN	I_{OL} = 64mA
I_{IH}	Input HIGH Current				5	µA	MAX	V_{IN} = V_{CC}
I_{IL}	Input LOW Current				–5	µA	MAX	V_{IN} = GND
I_{IH}	Input HIGH Current[3]				5	µA	MAX	V_{IN} = 2.7V
I_{IL}	Input LOW Current[3]				–5	µA	MAX	V_{IN} = 0.5V
I_{OZH}	Off State I_{OUT} HIGH-Level Output Current				10	µA	MAX	V_{OUT} = V_{CC}
I_{OZL}	Off State I_{OUT} LOW-Level Output Current				–10	µA	MAX	V_{OUT} = GND
I_{OZH}	Off State I_{OUT} HIGH-Level Output Current				10	µA	MAX	V_{OUT} = 2.7V
I_{OZL}	Off State I_{OUT} LOW-Level Output Current				–10	µA	MAX	V_{OUT} = 0.5V
I_{OS}	Output Short Circuit Current[2]		–60			mA	MAX	V_{OUT} = 0.0V
C_{IN}	Input Capacitance[3]			5	10	pF	MAX	All inputs
C_{OUT}	Output Capacitance[3]			9	12	pF	MAX	All outputs

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Notes:

1. Typical limits are at V_{CC} = 5.0V, T_A = +25°C ambient.
2. Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{os} tests should be performed last.
3. This parameter is guaranteed but not tested.

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DC CHARACTERISTICS (Over recommended operating conditions unless otherwise specified.)

Symbol	Parameter	Typ[1]	Max	Units	Conditions
I_{CC}	Quiescent Power Supply Current (CMOS inputs)	0.003	0.5	mA	V_{CC} = MAX, f_1 = 0, Outputs Open, $V_{IN} \leq 0.2V$ or $V_{IN} \geq V_{CC} - 0.2V$
ΔI_{CC}	Quiescent Power Supply Current (TTL inputs)	0.5	2.0	mA	V_{CC} = MAX, V_{IN} = 3.4V[2], f_1 = 0, Outputs Open
I_{CCD}	Dynamic Power Supply Current[3]	0.15	0.25	mA/ mHz	V_{CC} = MAX, One Input Toggling, 50% Duty Cycle, $\overline{OE}$ = GND, $V_{IN} \leq 0.2V$ or $V_{IN} \geq V_{CC} - 0.2V$, Outputs Open, LE = V_{CC}
I_C	Total Power Supply Current[5]	1.7	4.0	mA	V_{CC} = MAX, LE = V_{CC}, 50% Duty Cycle, Outputs Open, One Bit Toggling at f_1 = 10MHz, $\overline{OE}$ = GND and $V_{IN} \leq 0.2V$ or $V_{IN} \geq V_{CC} - 0.2V$
		2.0	5.0	mA	V_{CC} = MAX, LE = V_{CC}, 50% Duty Cycle, Outputs Open, One Bit Toggling at f_1 = 10MHz, $\overline{OE}$ = GND and V_{IN} = 3.4V or V_{IN} = GND
		3.2	6.5[4]	mA	V_{CC} = MAX, LE = V_{CC}, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f_1 = 2.5MHz, $\overline{OE}$ = GND and $V_{IN} \leq 0.2V$ or $V_{IN} \geq V_{CC} - 0.2V$
		5.2	14.5[4]	mA	V_{CC} = MAX, LE = V_{CC}, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f_1 = 2.5MHz, $\overline{OE}$ = GND and V_{IN} = 3.4V or V_{IN} = GND

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Notes:

1. Typical values are at V_{CC} = 5.0V, +25°C ambient and maximum loading.
2. Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.
3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
4. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.
5. $I_{CC} = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
   $I_{CC} = I_{CCQC} + I_{CCQT} D_H N_T + I_{CCD}(f_0/2 + f_1 N_1)$
   I_{CCQC} = Quiescent Current with CMOS input levels
   I_{CCQ} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)
   D_H = Duty Cycle for TTL Inputs High
   N_T = Number of TTL Inputs at D_H
   I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
   f_0 = Clock Frequency for Register Devices (Zero for Non-Register Devices)
   f_1 = Input Frequency
   N_1 = Number of Inputs at f_1
   All currents are in milliamps and all frequencies are in megahertz.

FUNCTION TABLES (Each Latch)

Inputs			Outputs 'FCT373—'FCT573
$\overline{OE}$	LE	D	O
L	H	H	H
L	H	L	L
L	L	X	Q_0
H	X	X	Z

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H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = HIGH Impedance
Q_0 = previous state of flip flops (Q_{n-1})

AC CHARACTERISTICS ('FCT373 — 'FCT573)

Sym.	Parameter	'FCT373 'FCT573				'FCT373A 'FCT573A				'FCT373C 'FCT573C				Units	Fig. No.
		MIL		COM'L		MIL		COM'L		MIL		COM'L			
		Min.[1]	Max.	Min.[1]	Max.	Min.[1]	Max.	Min.[1]	Max.	Min.[1]	Max.	Min.[1]	Max.		
t_{PLH} t_{PHL}	Prop Delay D_n to O_n	1.5	8.0	1.5	7.0	1.5	5.6	1.5	5.2	1.5	5.1	1.5	4.2	ns	1, 3
t_{PLH} t_{PHL}	Prop Delay LE to O_n	2.0	10.0	2.0	9.0	2.0	9.6	2.0	8.5	2.0	8.0	2.0	5.5	ns	1, 5
t_{PZH} t_{PZL}	Output Enable Time	1.5	10.0	1.5	9.0	1.5	7.5	1.5	6.5	1.5	6.3	1.5	5.5	ns	1, 7, 8
t_{PHZ} t_{PLZ}	Output Disable Time	1.5	8.5	1.5	7.5	1.5	6.5	1.5	5.5	1.5	5.9	1.5	5.0	ns	

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AC CHARACTERISTICS

Sym.	Parameter	'FCT373 'FCT573				'FCT373A 'FCT573A				'FCT373C 'FCT573C				Units	Fig. No.
		MIL		COM'L		MIL		COM'L		MIL		COM'L			
		Min.[1]	Max.	Min.[1]	Max.	Min.[1]	Max.	Min.[1]	Max.	Min.[1]	Max.	Min.[1]	Max.		
$t_s(H)$ $t_s(L)$	Setup Time, High to Low D_n to LE	2.0	–	2.0	–	2.0	–	2.0	–	2.0	–	2.0	–	ns	9
$t_n(H)$ $t_n(L)$	Hold Time, High to Low D_n to LE	1.5	–	1.5	–	1.5	–	1.5	–	1.5	–	1.5	–	ns	
$t_w(H)$	LE Pulse Width High	6.0	–	6.0	–	6.0	–	5.0	–	6.0	–	5.0	–	ns	5

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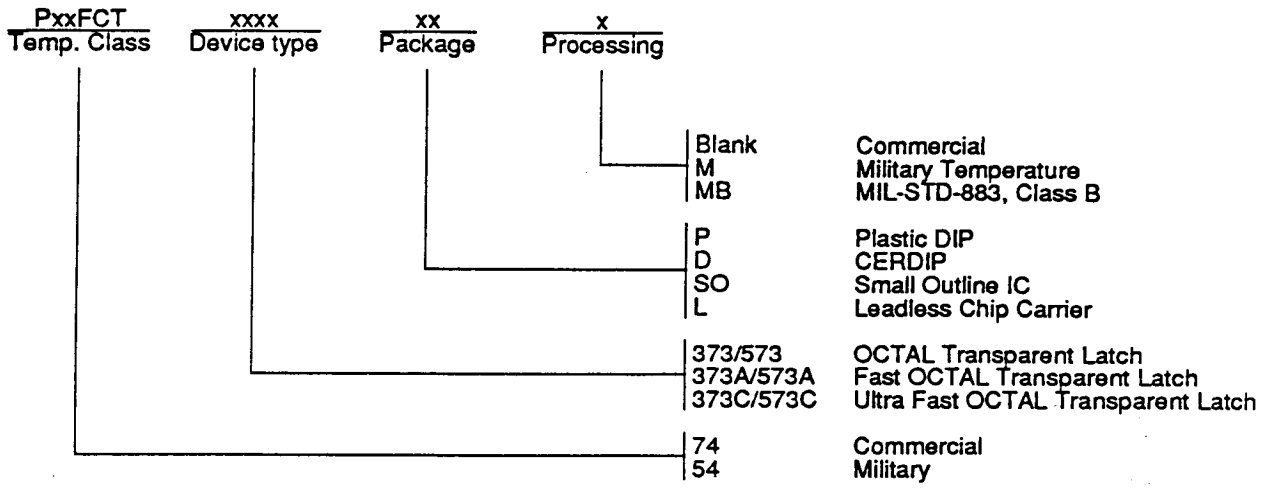
Note:

1. Minimum limits are guaranteed but not tested on Propagation Delays.
   AC Characteristics guaranteed with C_L = 50 pF as shown in Figure 1.

ORDERING INFORMATION



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